



**DMP2070U** 

#### P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	Ι <sub>D</sub> T <sub>A</sub> = +25°C
	44mΩ @ V <sub>GS</sub> = -4.5V	-4.6A
-20V	57mΩ @ V <sub>GS</sub> = -2.5V	-4A
	74mΩ @ V <sub>GS</sub> = -1.8V	-3.5A

#### **Features**

- Low On-Resistance
- Low Input Capacitance •
- Fast Switching Speed
- Low Input/Output Leakage ٠
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Loadswitch

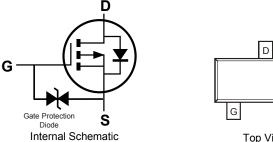
#### **Mechanical Data**

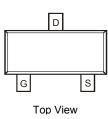
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020 ٠
- Terminals: Finish-Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (C3)
- Terminal Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



SOT23

Top View





#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2070U-7	SOT23	3,000 / Tape & Reel
DMP2070U-13	SOT23	10,000 / Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**

Notes:

I	MT4	MΥ	
Г			

MT4 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key			_		-							
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н		J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



#### Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	-20	V	
Gate-Source Voltage	V <sub>GSS</sub>	±8	V	
Continuous Drain Current (Note 7) $V_{GS}$ = -4.5V	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	ID	-4.6 -3.7	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	-20	A
Maximum Continuous Body Diode Forward Current (Note 6)	I <sub>S</sub>	-1.9	A	
Avalanche Current, L = 0.1mH (Note 8)	IAS	-14	A	
Avalanche Energy, L = 0.1mH (Note 8)		E <sub>AS</sub>	10	mJ

#### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.83	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	153	°C/W
Total Power Dissipation (Note 6)		PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ hetaJA}$	90	°C/W
Thermal Resistance, Junction to Case (Note 7)		$R_{ ext{ heta}JC}$	15.1	C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

#### Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						-
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	—	—	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = -1mA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	—	-1	μA	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	_	—	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.45		-0.95	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$
		_	37	44		$V_{GS}$ = -4.5V, $I_{D}$ = -2A
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	48	57	mΩ	V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -2A
		_	65	74		V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -2A
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.1	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -2.1A
DYNAMIC CHARACTERISTICS (Note 10)						-
Input Capacitance	Ciss	_	118	—		
Output Capacitance	C <sub>oss</sub>	_	79	—	pF	V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V f = 1MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	_	11	—		
Gate Resistance	R <sub>G</sub>	_	459	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = -8V)	Qg	_	8.2	—		
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	17.8	—	nC	$y_{1} = 10y_{1} = 20$
Gate-Source Charge	Q <sub>gs</sub>	_	1.4	—		$V_{DD} = -10V, I_D = -2A$
Gate-Drain Charge	Q <sub>gd</sub>	_	1.2	—		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	115	—		
Turn-On Rise Time	t <sub>R</sub>		304	—	1	V <sub>GS</sub> = -4.5V, V <sub>DD</sub> = -10V,
Turn-Off Delay Time	t <sub>D(OFF)</sub>		780	—	ns	$R_{G} = 1\Omega, I_{D} = -2A$
Turn-Off Fall Time	tF	—	666	—		

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

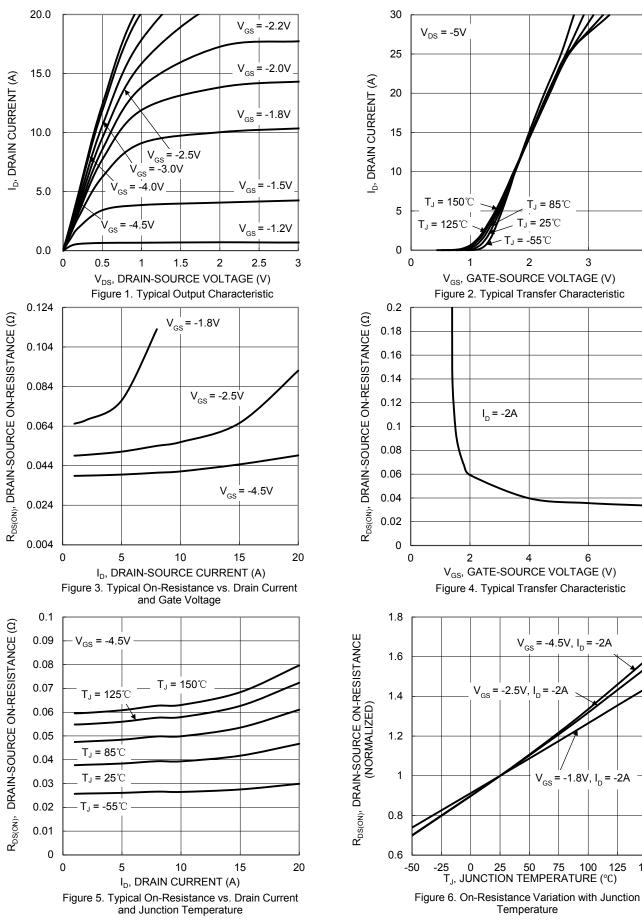
bevice mounted on FR-4 PC board, with minimum recommended bad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.





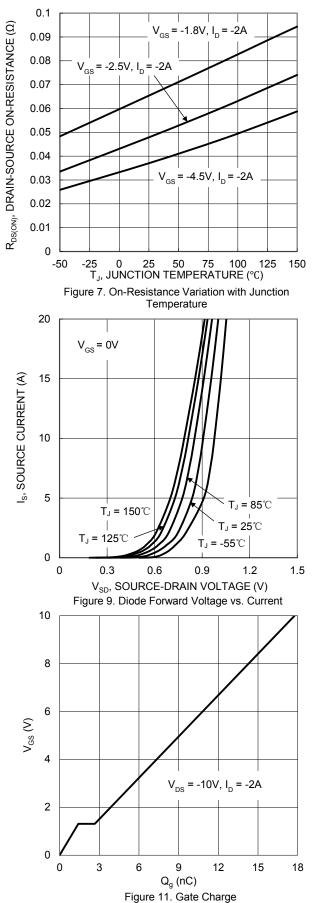
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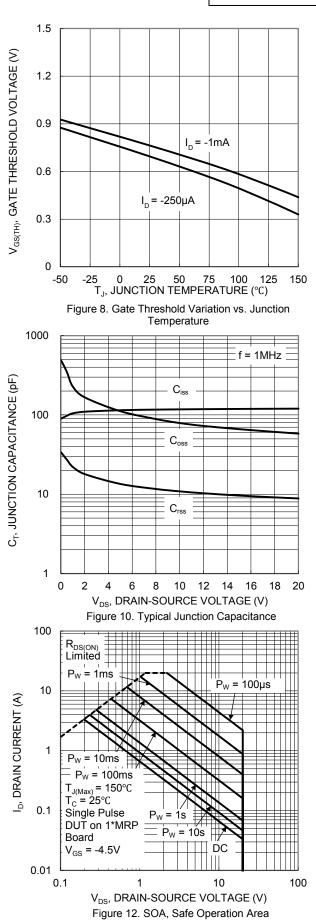
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150

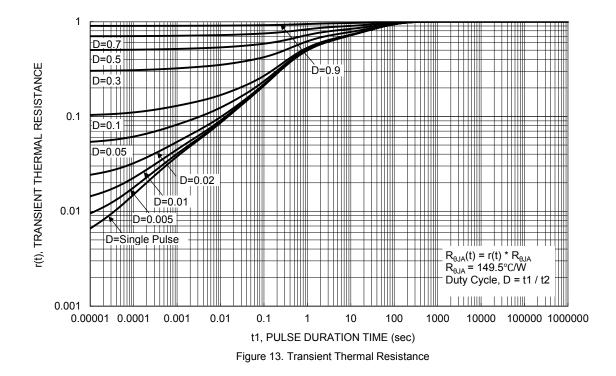






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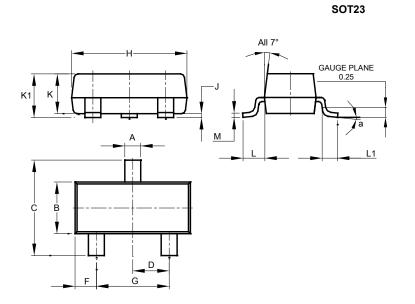






# **Package Outline Dimensions**

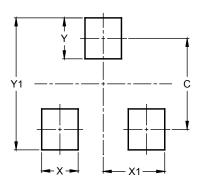
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
κ	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
Μ	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

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